

# dB-8059 Solid State Power Amplifier



GaN Solid State Power Amplifier 200W CW 2.0 – 18.0 GHz

The dB-8059 is a GaN Solid State Power Amplifier operating in the frequency range of 2 to 18 GHz providing up to 200 Watts at midband. The power supply topology uses proprietary low-noise, high-efficiency designs to operate the RF signal path. An embedded micro-controller provides the interface, control and protection functions and status indication for the Amplifier. Standard interface protocol for remote operation is RS-485. Other protocols such as RS-232, RS-422, Ethernet, CANBUS or custom interfaces are available as options. The TWT Amplifier is encased in an environmentally sealed package for outdoor and antenna pedestal mounted applications, and uses integral forced-air cooling for thermal management.

### **Features**

- Wideband GaN SSPA
- · 2.0 to 18 GHz, 200 W, CW
- 28 VDC, 270 VDC or 3 phase 400 Hz
- · Small and lightweight
- Forced Aircooling with integrated fans

### **Applications**

- Electronic countermeasures (ECM)
- Electronic warfare (EW) and simulations
- · Multi-band communication systems

### dB-8059 Solid State Power Amplifier Specifications

#### **Electrical**

Frequency Range 2.0 to 18.0 GHz

Output Power CW (with coolant

at 20° C)

150 watts from 2-4 GHz 200 watts from 4-9 GHz 150 watts from 9 to 16 GHz 100 watts from 16 to 18 GHz

Small Signal Gain 50 dB, min.

RF Input Power for Saturation 0 +/- 1 dBm

Duty Cycle 100% (CW)

Input VSWR 2.0:1, max.

Output VSWR 2.0:1, max.

Load VSWR 1.5:1, max., Full Spec Compliance

Load VSWR 2.5:1, max, No Damage

Prime Input Voltage 28 VDC, 270 VDC, or 3 phase 400 Hz, 60 Hz

1600W max

Prime Power 1400W typical

Interface Control RS-485

Mechanical

Dimensions 15.0" (L) x 13.0" (W) x 12.0" (H)

Weight 100 lbs., nominal

Cooling Built in forced air cooling

Connectors:

Prime Power MS3112 series
Control/Status MS3112E14-18
RF Input Type SMA (F)

**Environmental** 

Ambient Temperature  $-40^{\circ}$  C to  $+40^{\circ}$  C Storage Temperature  $-54^{\circ}$  C to  $+90^{\circ}$  C

Operating Altitude Up to 15,000 feet ASL

Humidity Mil-Std 810
Salt Fog Mil-Std 810
Rain Mil-Std 810

Specifications subject to change without notice.



## Reliability by Design®



#### About dB Control

Established in 1990, dB Control Corp., a subsidiary of the Electronic Technologies Group (ETG) of HEICO Corp., supplies mission-critical, often sole-source, products worldwide to military organizations, as well as to major defense contractors and commercial manufacturers. dB Control designs and manufactures reliable high-power TWT Amplifiers (TWTAs), microwave power modules (MPMs), transmitters and power supplies with modulators for radar, electronic countermeasures (ECM) and data link applications. The company's high-power amplifiers use solid state, as well as vacuum electron devices and cover the 1 to 50 GHz frequency range. The modularity of dB Control's designs enables rapid configuration of custom products for a variety of platforms, including ground-based and high-altitude military manned and unmanned aircraft. dB Control has an outstanding record of successfully repairing, refurbishing and replacing tightly packaged high-voltage transformers, assemblies and power supplies. The company offers specialized contract manufacturing, transformer winding and testing, full vacuum encapsulation, pressure cure, conformal coating and repair depot services from its modern 40,000 square foot facilities in Fremont, California, www.dBControl.com AS-9100D and ISO-9001:2015 Certified.

